NSN 5961-01-169-4228 Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-169-4228
Inclosure Material:
Metal
Overall Length:
0.550 inches
Terminal Length:
0.620 inches
Internal Configuration:
Junction contact
Electrode Internally-electrically Connected To Case:
Anode
Mounting Method:
Terminal
Features Provided:
Hermetically sealed case
Overall Width Across Flats:
0.562 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
700.0 repetitive peak off-state voltage and 700.0 repetitive peak reverse voltage and 960.0 nonrepetitive peak reverse voltage
Current Rating Per Characteristic:
250.00 milliamperes forward current, total rms preset
Power Rating Per Characteristic:
40.0 watts small-signal input power, common-collector not applicable
Maximum Operating Tempurature Per Measurement Point:
125.0 degrees celsius junction
Special Features:
Junction pattern arrangement: pnpn
Terminal Type And Quantity:
2 tab, solder lug and 1 case
Shelf Life:
N/a
Unit Of Measure:
<del>-</del>
Demilitarization:
No
Fiig:
A110a0